
2SK2114, 2SK2115

Silicon N-Channel MOS FET

HITACHI

ADE-208-1346 (Z)

1st. Edition

Mar. 2001

Application

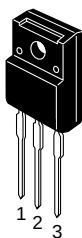
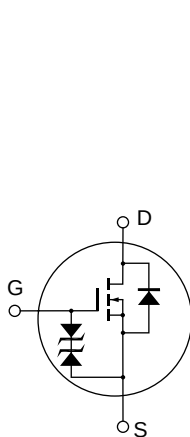
High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for Switching regulator

Outline

TO-220CFM



1. Gate
2. Drain
3. Source

2SK2114, 2SK2115

Absolute Maximum Ratings (Ta = 25°C)

Item		Symbol	Ratings	Unit
Drain to source voltage	2SK2114	V_{DSS}	450	V
	2SK2115	V_{DSS}	500	
Gate to source voltage		V_{GSS}	± 30	V
Drain current		I_D	5	A
Drain peak current		$I_{D(pulse)}^{*1}$	20	A
Body to drain diode reverse drain current		I_{DR}	5	A
Channel dissipation		P_{ch}^{*2}	35	W
Channel temperature		T_{ch}	150	°C
Storage temperature		T_{stg}	-55 to +150	°C

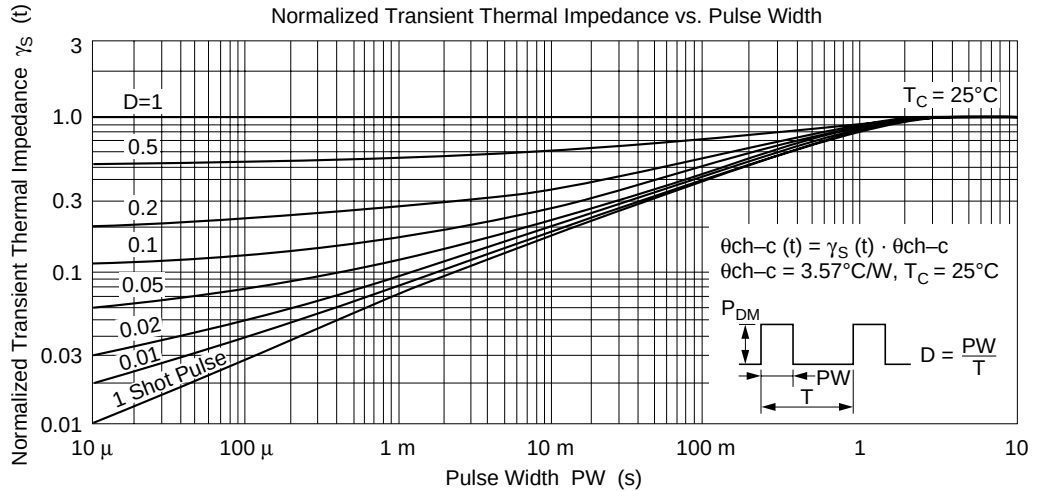
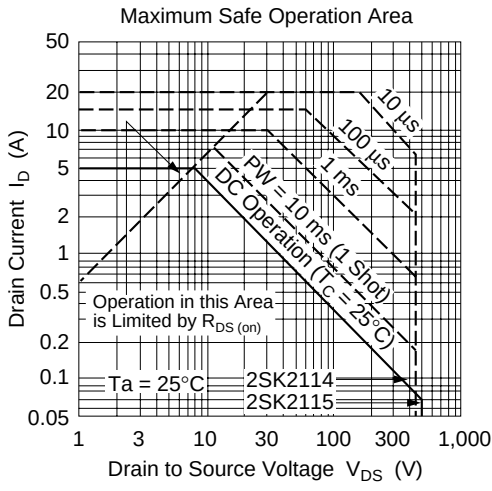
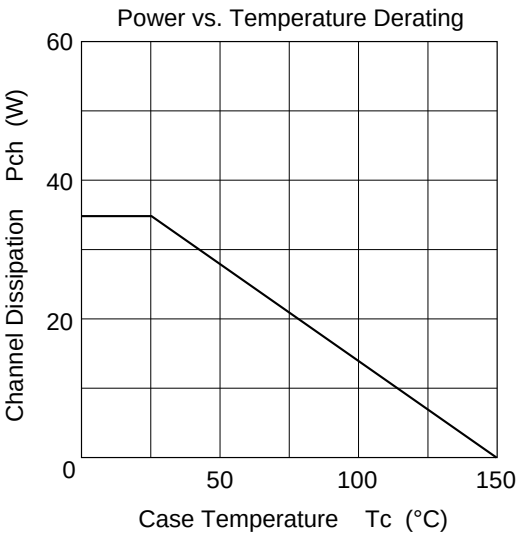
Notes 1. $PW \leq 10 \mu s$, duty cycle $\leq 1 \%$
2. Value at $T_c = 25^\circ C$

Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Item		Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	2SK2114 2SK2115	$V_{(BR)DSS}$	450 500	—	—	V	$I_D = 10\text{ mA}$, $V_{GS} = 0$
Gate to source breakdown voltage		$V_{(BR)GSS}$	± 30	—	—	V	$I_G = \pm 100\text{ }\mu\text{A}$, $V_{DS} = 0$
Gate to source leak current		I_{GSS}	—	—	± 10	μA	$V_{GS} = \pm 25\text{ V}$, $V_{DS} = 0$
Zero gate voltage drain current	2SK2114 2SK2115	I_{DSS}	—	—	250	μA	$V_{DS} = 360\text{ V}$, $V_{GS} = 0$ $V_{DS} = 400\text{ V}$, $V_{GS} = 0$
Gate to source cutoff voltage		$V_{GS(off)}$	2.0	—	3.0	V	$I_D = 1\text{ mA}$, $V_{DS} = 10\text{ V}$
Static drain to source on state resistance	2SK2114 2SK2115	$R_{DS(on)}$	— —	1.0 1.2	1.4 1.5	Ω	$I_D = 2.5\text{ A}$, $V_{GS} = 10\text{ V}^{*1}$
Forward transfer admittance		$ y_{fs} $	2.5	4.0	—	S	$I_D = 2.5\text{ A}$ $V_{DS} = 10\text{ V}^{*1}$
Input capacitance		C_{iss}	—	640	—	pF	$V_{DS} = 10\text{ V}$
Output capacitance		C_{oss}	—	160	—	pF	$V_{GS} = 0$
Reverse transfer capacitance		C_{rss}	—	20	—	pF	$f = 1\text{ MHz}$
Turn-on delay time		$t_{d(on)}$	—	10	—	ns	$I_D = 2.5\text{ A}$
Rise time		t_r	—	25	—	ns	$V_{GS} = 10\text{ V}$
Turn-off delay time		$t_{d(off)}$	—	50	—	ns	$R_L = 12\text{ }\Omega$
Fall time		t_f	—	30	—	ns	
Body to drain diode forward voltage		V_{DF}	—	0.95	—	V	$I_F = 5\text{ A}$, $V_{GS} = 0$
Body to drain diode reverse recovery time		t_{rr}	—	300	—	ns	$I_F = 5\text{ A}$, $V_{GS} = 0$, $di_F / dt = 100\text{ A} / \mu\text{s}$

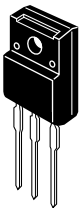
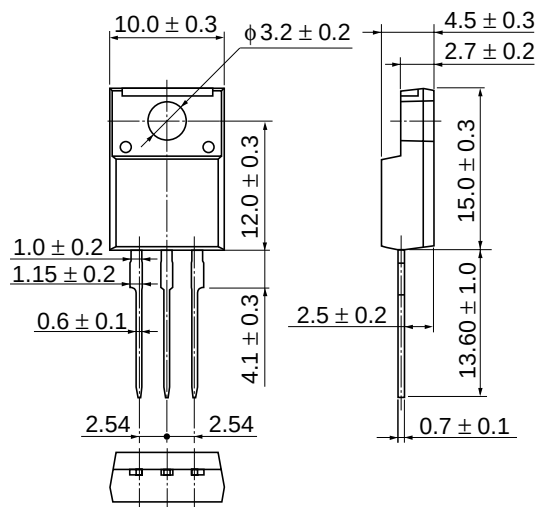
Note 1. Pulse Test

See characteristics curve of 2SK1155, 2SK1156.



Package Dimensions

As of January, 2001
Unit: mm



Hitachi Code	TO-220CFM
JEDEC	—
EIAJ	—
Mass (reference value)	1.9 g

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